NSN 5962-01-331-7106

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-331-7106 **Overall Height:** 0.400 inches **Body Length:** 1.060 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.140 inches and 0.185 inches **Maximum Power Dissipation Rating:** 1.2 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Bipolar and programmable and monolithic and bidirectional **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Bipolar metal-oxide semiconductor **Input Circuit Pattern:** 16 input **Case Outline Source And Designator:** D-8 mil-m-38510 **Current Rating Per Characteristic:** 12.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 5.0 volts power source **Memory Device Type:** Pal **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 20 printed circuit Shelf Life: N/a

--

Unit Of Measure:

NSN 5962-01-331-7106

Memory Microcircuit - Page 2 of 2



Demilitarization:

Yes - demil/mli

Fiig:

A458a0